

## MBR2035/2045CT MBRB2035/2045CT MBR2035/2045CT-1

## Data Sheet N0186, Rev. A MBR2035/2045CT MBRB2035/2045CT MBR2035/2045CT-1 SCHOTTKY RECTIFIER

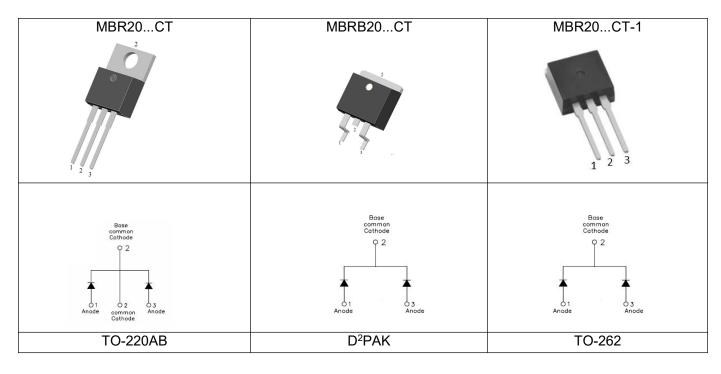
### Features

**Technical Data** 

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection



### Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V <sub>RRM</sub> V <sub>RWM</sub>	-	35	MBR2035CT	V
DC Blocking Voltage	VRWM VR		45	MBR2045CT	v
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=95°C, rectangular wave form		10(Per Leg) )(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse, $T_C$ = 25 °C		200	А

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 10A, Pulse, T <sub>J</sub> = 25 °C	0.57	0.70	V
(Per Leg)*	V <sub>F2</sub>	@ 10A, Pulse, T <sub>J</sub> = 125 °C	0.55	0.60	V
Reverse Current (Per Leg)*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	0.03	1.0	mA
	I <sub>R2</sub>	$@V_R = rated V_R$ T <sub>J</sub> = 125 °C	9	15	mA
Junction Capacitance(Per Leg)	CT	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	220	600	pF
Typical Series Inductance (Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300  $\mu s, \ duty \ cycle < 2\%$ 

### **Thermal-Mechanical Specifications:**

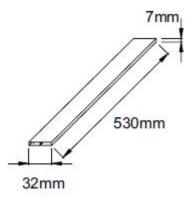
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>0JC</sub>	DC operation	2.0	°C/W
Case Style	TO-220AB D <sup>2</sup> PAK TO-262			

### **Tube Specification**

Device	Package	Weight	Shipping
MBR20CT	TO-220AB	1.8g	50pcs / tube
MBRB20CT	D <sup>2</sup> PAK	1.85g	800pcs / reel
MBR20CT-1	TO-262	1.85g	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

### Tube Specification(TO-220AB/TO-262)





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**TJ=125**℃

TJ=25℃

60

70

80

90

100

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# RoHS

#### **Ratings and Characteristics Curves** 100 10000 Junction Capacitance-CT(PF) Reverse Current-IR(MA) 10 1000 1 **TJ=25**℃ 0.1 100 0.01 10 0.001 20 25 30 20 0 5 10 15 35 40 10 30 40 Reverse Voltage-VR(V) **Reverse Voltage-VR(%)**

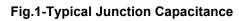
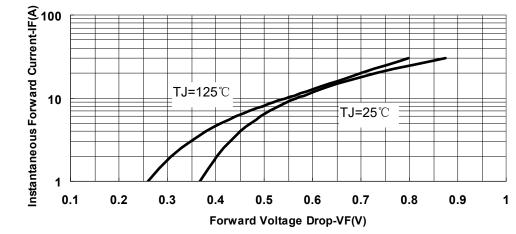
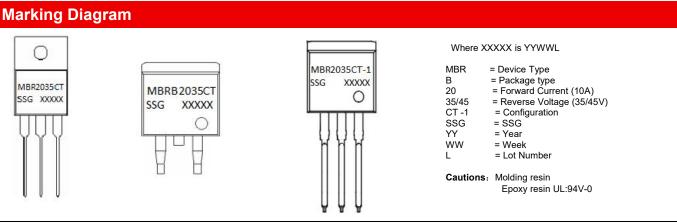


Fig.2-Typical Reverse Characteristics

50







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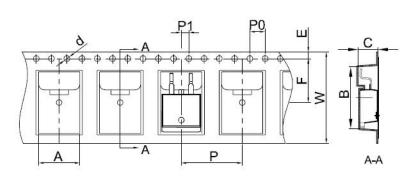


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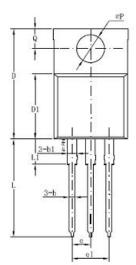
## Carrier Tape Specification D<sup>2</sup>PAK

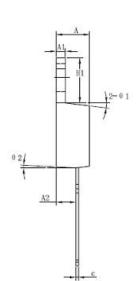


Symbol	Millimeters		
Symbol	Min.	Max.	
A	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

### **Mechanical Dimensions TO-220AB**







Symbol	Dimensions in millimeters		
	Min	Typical	Max
A	3.56	-	4.83
A1	0.51	-	1.40
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	9.65	-	10.67
е	-	2.54	-
e1	-	5.08	-
H1	5.84	-	6.86
L	12.70	-	14.73
L1	-	-	6.35
ΦΡ	-	3.56	-
Q	2.54	-	3.43



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Max.

4.85

0.25

2.89

0.96

0.61

1.37

8.85

10.31

10.18

15.6

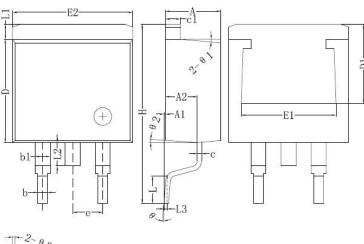
2.70

1.40

2.20

**8°** 

### Mechanical Dimensions D<sup>2</sup>PAK

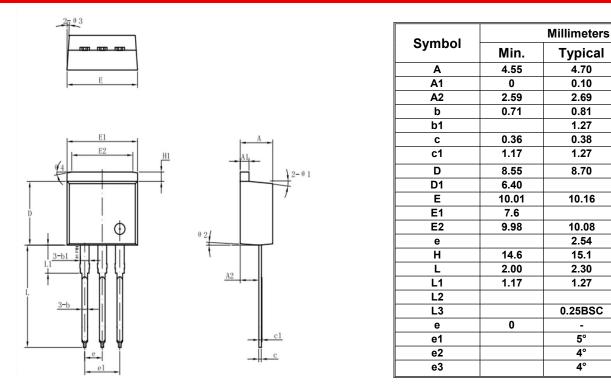


		-	e—I	
-2	θ3			
	Π			
	U			

Symbol	Dimensions in millimeters		
,	Min.	Max.	
A	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	8.65	
D1	6.86		
E1	6.22		
E2	9.65	10.67	
е	2.54BSC		
Н	14.60	15.88	
L	1.78	2.80	
L1	-	1.68	
L2	- 1.78		
L3	0.255BSC		
Θ	0	8°	

Г

### **Mechanical Dimensions TO-262**



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